

Low Voltage, 0.7 Ω , Triple SPDT Analog Switch

DESCRIPTION

The DG2753 is a low voltage, low on-resistance, triple single-pole/double-throw (SPDT) monolithic CMOS analog switch. The device is designed for operation from 1.65 V to 4.3 V single supply. The device is 1.8 V logic compatible within the full operation voltage range to interface with low voltage DSP or MCU control logic. These traits make it ideal for one cell Li-ion battery direct power in portable applications.

The DG2753 fully guarantees operation when V+ is as low as 1.8 V. When powered from a 3 V power supply, it has a 0.9 Ω on-resistance, with 0.1 Ω R_{ON} matching between channels, and 0.2 Ω (Max) R_{ON} flatness.

Each switch conducts signals across power rails equally well in both directions when on, and blocks up to the power supply level when off. It offers 30 nS $T_{\rm on}$ and 10 nS $T_{\rm off}$. Breakbefore-make is guaranteed.

The DG2753 is built on Vishay Siliconix's low voltage process. An epitaxial layer prevents latchup.

It is available in QFN16 3 x 3 mm and TSSOP16 packages. As a committed partner to the community and the environment, Vishay Siliconix manufactures this product with lead (Pb)-free device terminations. For analog switching products manufactured in QFN packages, the lead (Pb)-free "-E4" suffix is being used as a designator for nickel-palladium-gold. The TSSOP-16 package is offered in lead (Pb)-free with 100 % matte Tin terminations. The "-E3" suffix is the designator. Both the 100 % matte Tin and nickel-palladium gold device terminations meet all JEDEC standards for reflow and MSL ratings.

FEATURES

- Low Voltage Operation (1.65 to 4.3 V)
- Low On-Resistance r_{ON} : 0.9 Ω at 2.7 V
- Fast Switching: T_{ON} = 30 ns
- T_{OFF} = 10 ns
- QFN-16 (3 x 3) Package
- Latch-Up Current > 300 mA (JESD78)

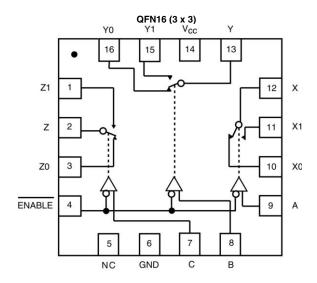
BENEFITS

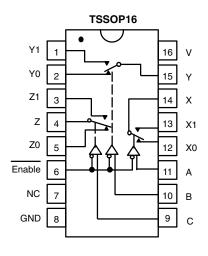
- Reduced Power Consumption
- High Accuracy
- · Reduce Board Space
- TTL/1.8 V Logic Compatible

APPLICATIONS

- Cellular Phones
- Speaker Headset Switching
- Audio and Video Signal Routing
- PCMCIA Cards
- · Battery Operated Systems

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION





| ORDERING INFORMATION | | | | | |
|----------------------|---|----------------|--|--|--|
| Temp Range | Package | Part Number | | | |
| - 40 to 85 °C | TSSOP-16 | DG2753DQ-T1-E3 | | | |
| | 16-Pin QFN (3 mm x 3 mm) Variation 2 | DG2753DN-T1-E4 | | | |

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| TRUTH TABLE | | | | | | |
|--------------|---|---------------|---|-------------------|--|--|
| Enable Input | | Select Inputs | | ON Switches | | |
| | С | В | Α | DG2753 | | |
| Н | X | Х | Х | All switches open | | |
| L | X | Х | L | X - X0 | | |
| L | X | Х | Н | X - X1 | | |
| L | X | L | Х | Y - Y0 | | |
| L | X | Н | Х | Y - Y1 | | |
| L | L | Х | Х | Z- Z0 | | |
| L | Н | Х | X | Z - Z1 | | |

X = Do not care

| ABSOLUTE MAXIMUM RATINGS $T_A = 25$ °C, unless otherwise noted | | | | | |
|---|------------------------------|---------------------|------|--|--|
| Parameter | | Limit | Unit | | |
| Defended to OND | V+ | - 0.3 to 5.0 | V | | |
| Reference to GND | IN, COM, NC, NO ^a | - 0.3 to (V+ + 0.3) | | | |
| Current (Any terminal except NO, NC or COM) | | 30 | | | |
| Continuous Current (NO, NC, or COM) | | ± 300 | mA | | |
| Peak Current (Pulsed at 1 ms, 10 % duty cycle) | | ± 500 | | | |
| Storage Temperature (D Suffix) | | - 65 to 150 | °C | | |
| Package Solder Reflow Conditions ^d | 16-Pin QFN (3 x 3 mm) | 250 | | | |
| Power Dissipation (Packages) ^b | QFN-16 ^c | 1385 | mW | | |

Notes:

- a. Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC Board.
- c. Derate 17.3 mW/°C above 70 °C.
- d. Manual soldering with iron is not recommended for leadless components. The QFN is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper lip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

| SPECIFICATIONS | | | | | | | |
|-------------------------------------|----------------------------|---|-------------------|--------------------------------|------------------|------------------|------|
| | | Test Conditions Otherwise Unless Specified | | Limits - 40 to 85 °C | | | |
| Parameter | Symbol | $V+$, \pm 10 %, $V_{IN} = 0.4$ or 1.8 V^e | Temp ^a | Min ^b | Typ ^c | Max ^b | Unit |
| Analog Switch | | | | | | | |
| Analog Signal Range ^d | V_{NO}, V_{NC}, V_{COM} | | Full | 0 | | V+ | ٧ |
| 0.5 | r _{DS(on)} | $V+ = 2.7 \text{ V}, I_{NO/NC} = 100 \text{ mA}, V_{COM} = 1.7 \text{ V}$ | Room | | 0.9 | 1.3 | Ω |
| | | $V+ = 2.7 \text{ V}, I_{NO/NC} = 100 \text{ mA}, V_{COM} = 1.7 \text{ V}$ | Full | | | 1.5 | |
| On-Resistance | | V+ = 4.2 V, I _{NO/NC} = 100 mA, V _{COM} = 2.1 V | Room | | 0.7 | 1.2 | |
| | | $V+ = 4.2 \text{ V}, I_{NO/NC} = 100 \text{ mA}, V_{COM} = 2.1 \text{ V}$ | Full | | | 1.4 | |
| r _{ON} Match | $\Delta r_{(on)}$ | $V+ = 2.7 \text{ V}, I_{NO/NC} = 100 \text{ mA}, V_{COM} = 1.7 \text{ V}$ | Room | | | 0.4 | |
| | | $V+ = 4.3 \text{ V}, I_{NO/NC} = 100 \text{ mA}, V_{COM} = 2.1 \text{ V}$ | Room | | | 0.6 | |
| r _{ON} Resistance Flatness | r _{(on) Flatness} | $V+ = 2.7 \text{ V}, I_{NO/NC} = 100 \text{ mA}, V_{COM} = 1.7 \text{ V}$ | Room | | | 0.2 | |
| Switch Off Leakage Current | I _{NO(off)} | $V+ = 4.3 \text{ V}, V_{NO}, V_{NC} = 4 \text{ V}/0.3 \text{ V},$ | Room Full | - 2 - 25 | | 2 25 | |
| | I _{COM(off)} | $V_{COM} = 0.3 \text{ V/4 V}$ | Room Full | - 2 - 25 | | 2 25 | nA |
| Channel-On Leakage Current | I _{COM(on)} | $V+ = 4.3 \text{ V}, V_{COM} = V_{NO}, V_{NC} = 0.3 \text{ V/4 V}$ | Room Full | - 2 - 10 | | 2 10 | |





| SPECIFICATIONS | | | | | | | | |
|--|-----------------------|--|-------------------|-------------------------|------------------|------------------|------|--|
| | | Test Conditions Otherwise Unless Specified | | Limits - 40 to 85 °C | | | | |
| Parameter | Symbol | $V+$, ± 10 %, V_{IN} = 0.4 or 1.8 V^e | Temp ^a | Min ^b | Typ ^c | Max ^b | Unit | |
| Digital Control | | | | | | | • | |
| Input High Voltage | V _{INH} | V+ = 1.8 V | Full | 1 | | | | |
| | | V+ = 3 V | Full | 1.4 | | | | |
| | | V+ = 4.3 V | Full | 1.8 | | | V | |
| | | V+ = 1.8 V | Full | | | 0.4 | V | |
| Input Low Voltage | V_{INL} | V+ = 3 V | Full | | | 0.5 | | |
| | | V+ = 4.3 V | Full | | | 0.5 | | |
| Input Current | I_{INL} , I_{INH} | $V_{IN} = 0 \text{ V or V} +$ | Full | - 1 | | 1 | μΑ | |
| Dynamic Characteristics | | | | | | | | |
| Turn-On Time | t _{ON} | V+ = 2.7 V | Room Full | | 30 | 60 65 | ns | |
| Turn-Off Time | t _{OFF} | V_{NO} , V_{NC} = 1.5 V, R_L = 50 Ω , C_L = 35 pF | Room Full | | 10 | 30 40 | | |
| Break-Before-Make | t _{OPEN} | V+ = 2.7 V | Full | 5 | 30 | | | |
| Adress Transistion Time | t _{TRANS} | V_{NO} , V_{NC} = 1.5 V, R_L = 50 Ω , C_L = 35 pF | Full | | 40 | 80 | | |
| Charge Injection ^d | Q _{INJ} | V+ = 2.7 V, C_L = 1 nF, R_{GEN} = 0 Ω , f = 500 kHz V_{NC} , V_{NO} = 2 V (test at COM side) | Room | | - 25 | | рС | |
| Off-Isolation ^d | O _{IRR} | V+ = 2.7 V, C_L = 1 nF, R_{GEN} = 0 Ω , f = 500 kHz V_{NC} , V_{NO} = 2 V (test at COM side) | Room | | - 90 | | dB | |
| Crosstalk ^d | X _{TALK} | $V+=2.7 \text{ V, } C_L=1 \text{ nF, } R_{GEN}=0 \Omega$ $V_{NC}, V_{NO}=2 \text{ V (test at }_{COM} \text{ side)}$ | Room | | - 90 | | — as | |
| N N Off Compositences | C _{NO(off)} | | Room | | 35 | | | |
| N _O , N _C Off Capacitance ^d | C _{NC(off)} | V _{IN} = 0 or V+, f = 1 MHz | Room | | 35 | | pF | |
| Channel/On Capacitance ^d | C _{NO(on)} | | Room | | 80 | | | |
| | C _{NC(on)} | | Room | | 80 | | 1 | |
| Power Supply | | | | | L | L | | |
| Power Supply Current | l+ | V _{IN} = 0 or V+ | Full | | | 1 | μΑ | |

Notes:

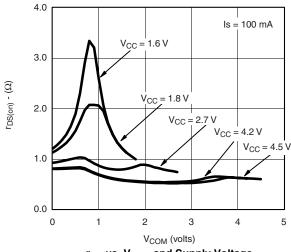
- a. Room = 25 $^{\circ}$ C, Full = as determined by the operating suffix.
- b. Typical values are for design aid only, not guaranteed nor subject to production testing.
- c. The algebraic convention where by the most negative value is a minimum and the most positive a maximum, is used in this datasheet.
- d. Guarantee by design, not subjected to production test.
- e. V_{IN} = input voltage to perform proper function.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

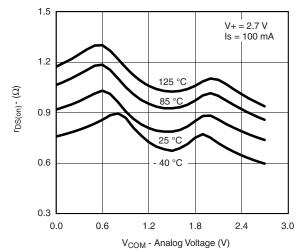
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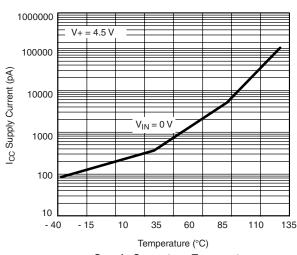
TYPICAL CHARACTERISTICS $T_A = 25$ °C, unless otherwise noted



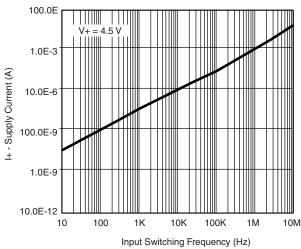
 $r_{\mbox{\scriptsize ON}}$ vs. $V_{\mbox{\scriptsize COM}}$ and Supply Voltage



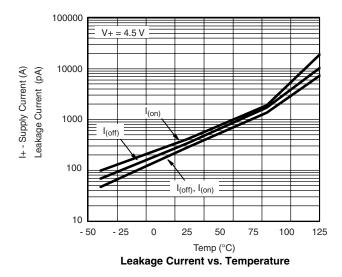
r_{ON} vs. Analog Voltage and Temperature



Supply Current vs. Temperature



Supply Current vs. Input Switching Frequency



2000 V+ = 4.5 V

1000 ICOM(on)

- 1000

- 2000

0 1 2 3 4 5

V_{COM} - Analog Voltage (V)

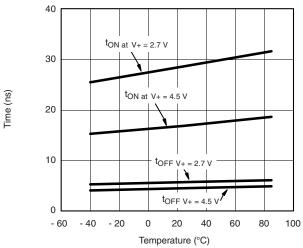
Leakage Current vs. Analog Voltage



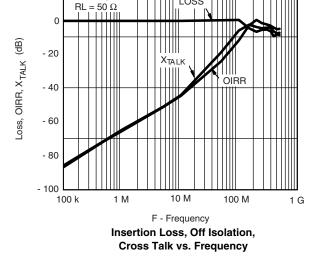




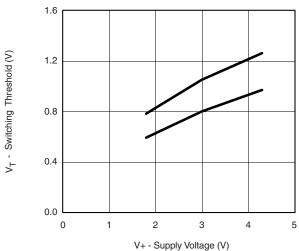
TYPICAL CHARACTERISTICS $T_A = 25$ °C, unless otherwise noted



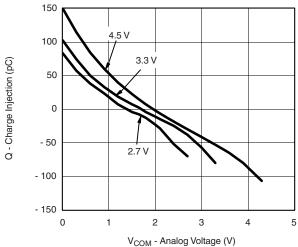
Switching Time vs Temperature



V + = 4.5 V



Switching Threshold vs. Supply Voltage



Charge Injection vs. Analog Voltage

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TEST CIRCUITS

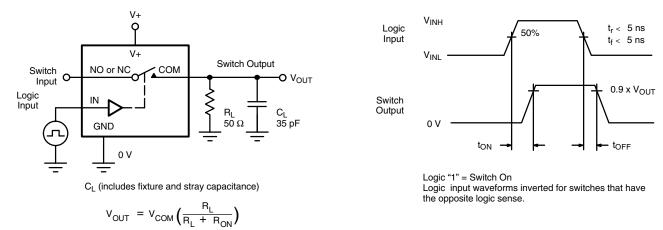


Figure 1. Switching Time

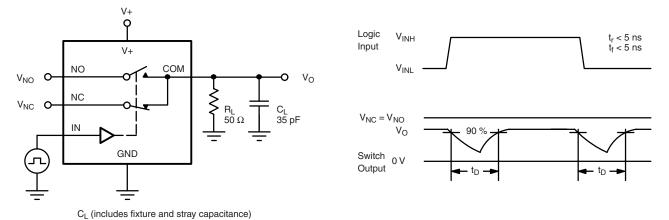


Figure 2. Break-Before-Make Interval

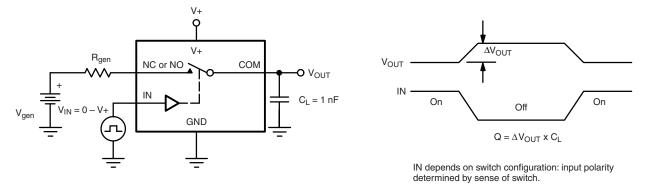


Figure 3. Charge Injection





TEST CIRCUITS

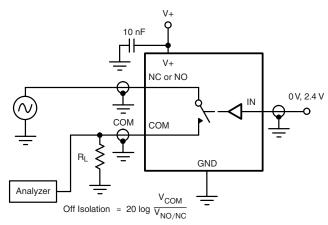


Figure 4. Off-Isolation

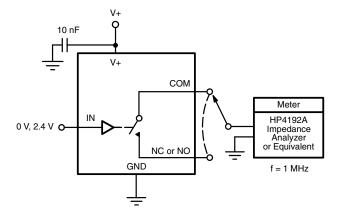


Figure 5. Channel Off/On Capacitance

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